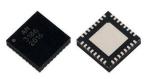
6 to 26.5 GHz Bandpass Filter Bank



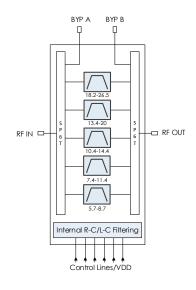
Description

AM3186 is a sub-octave fixed bandpass filter bank covering the 6 GHz to 26.5 GHz frequency range. The filter bank contains 5 bandpass filters with full 1 GHz overlap as well as an integrated, low-loss filter bypass path. AM3186 is an excellent front-end filter bank for a broadband receiver, or transmitter. AM3186 is packaged in a 5mm QFN package and operates over the -40C to +85C temperature range.



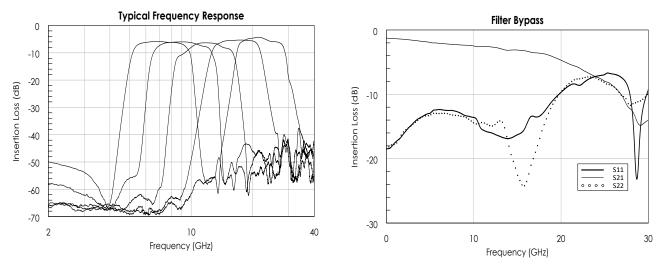
Features

- Sub-Octave Filter Bank
- Integrated Switches
- Integrated Control Line Filtering
- 6 dB Insertion Loss
- 20 GHz Bypass Path
- +36 dBm IIP3
- +5.0 V Supply
- +3.3 to +5.0 V Control
- 5mm QFN Package
- -40C to +85C Operation
- 5mm QFN package



Functional Diagram

Characteristic Performance



6 to 26.5 GHz Bandpass Filter Bank



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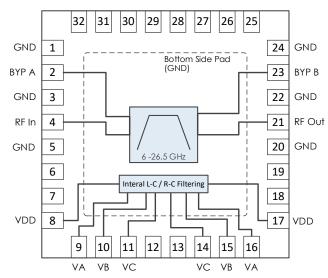
Revision History

Date	Revision Number	Notes
June 10, 2020	1	Initial Release
June 15, 2021	2	Updated figures and picture



Pin Layout and Definitions

Note: All Non-Named Pins are GND



Pin Number	Pin Name	Pin Function
1	GND	Ground – Common
2	BYP A	Filter Bypass A Side – 50 Ohms – DC Coupled, External DC Blocking Cap Required
3	GND	Ground – Common
4	RF In	RF Input – 50 Ohms – DC Coupled, External DC Blocking Cap Required
5-7	GND	Ground – Common
8	VDD	DC Power Input
9	VA	Switch Control A*
10	VB	Switch Control B**
11	VC	Switch Control C***
12, 13	GND	Ground – Common
14	VC	Switch Control C***
15	VB	Switch Control B**
16	VA	Switch Control A*
17	VDD	DC Power Input
18-20	GND	Ground – Common
21	RF Out	RF Output – 50 Ohms – DC Coupled, External DC Blocking Cap Required
22	GND	Ground – Common
23	BYP B	Filter Bypass B Side – 50 Ohms – DC Coupled, External DC Blocking Cap Required
24-32	GND	Ground – Common
Bottom Pad	GND	Ground – Common

* Pins 9 and 16 can be directly connected on board

** Pins 10 and 15 can be directly connected on board

*** Pins 11 and 14 can be directly connected on board



Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+6.0 V
RF Input Power		+27 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.

Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+5.0 V	+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C



DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage		+3.0 V	+5.0 V	+5.2 V
DC Supply Current	VDD = +5.0 V		18 mA	
Power Dissipated	VDD = +5.0 V		90 mW	
Logic Level Low		-0.1 V		+0.5 V
Logic Level High		+2.0 V		+VDD V

RF Performance

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		6 GHz		26.5 GHz
Insertion Loss	VDD = +5.0 V, Band 1		-6 dB	
	VDD = +5.0 V, Band 2		-6.3 dB	
	VDD = +5.0 V, Band 3		-6.5 dB	
	VDD = +5.0 V, Band 4		-5.5 dB	
	VDD = +5.0 V, Band 5		-5 dB	
Return Loss	VDD = +5.0 V		< -10 dB	
Input IP3	VDD = +5.0 V		+36 dBm	

Timing Characteristics

Parameter	Minimum	Typical	Maximum
Band Switching Speed		200 ns	
Note: Timing characteristics measured from 50% control to 90% RF.			

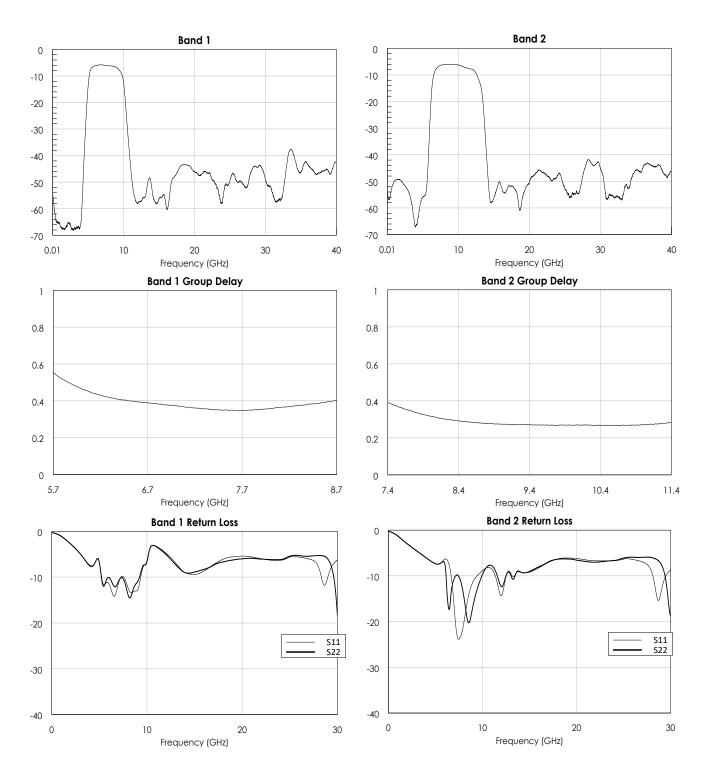
State Table

VC	VB	VA	Filter Band
L	L	L	Bypass Enabled
L	L	Н	5.7 – 8.7 GHz
L	Н	L	7.4 – 11.4 GHz
L	Н	Н	10.4 – 14.4 GHz
Н	L	L	13.4 – 20 GHz
Н	L	Н	18.2 – 26.5 GHz

6 to 26.5 GHz Bandpass Filter Bank

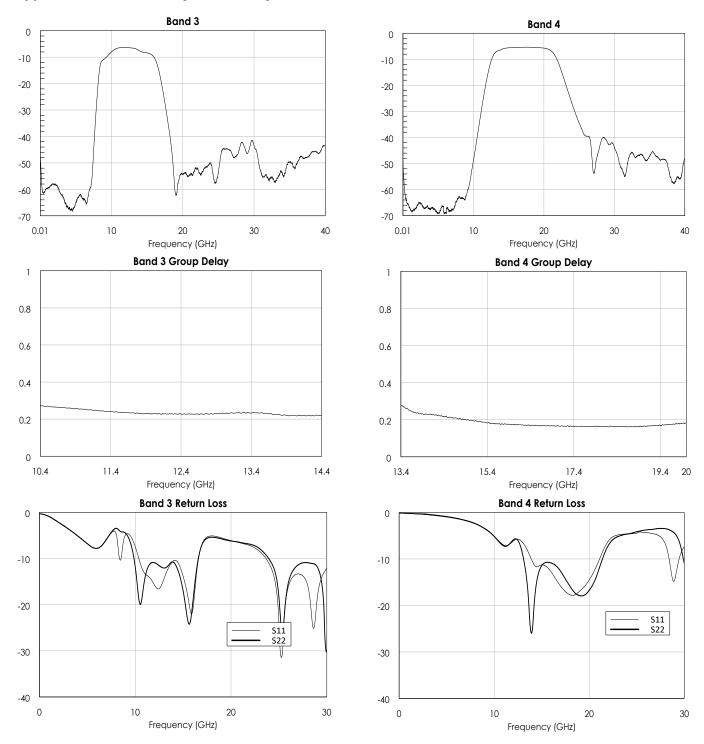


Typical Performance



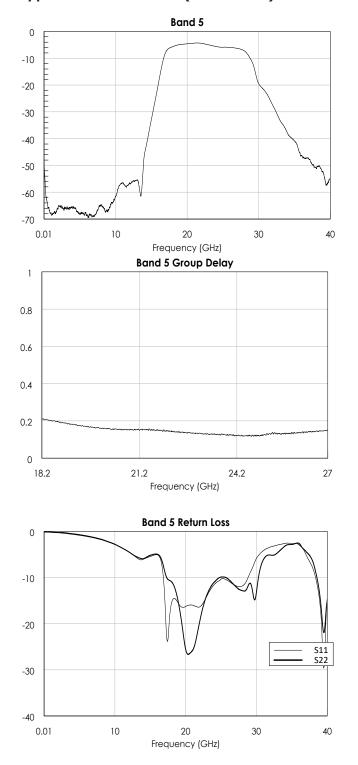


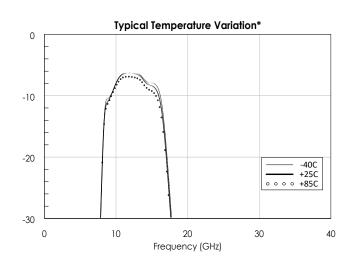
Typical Performance (continued)





Typical Performance (continued)

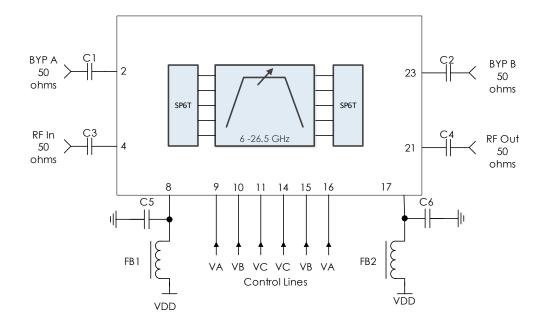




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6 to 26.5 GHz Bandpass Filter Bank

Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1-C4	0.1 µF	0201BB104KW160	Passives Plus
FB1, FB2	Ferrite bead	MMZ1005A222E	TDK
C5, C6	0.1 µF	C1005X7R1H104K050BB	TDK

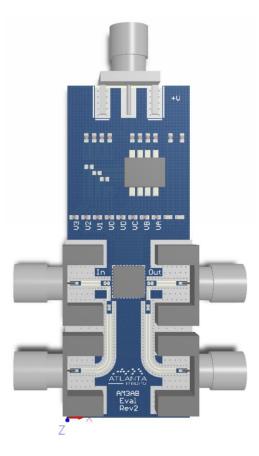
Notes:

- 1. Control lines filtered internally providing high frequency isolation.
- 2. DC blocking capacitors should be low-loss, broadband capacitors for optimum performance.
- 3. Pins 9 and 16 can be directly connected on board.
- 4. Pins 10 and 15 can be directly connected on board.
- 5. Pins 11 and 14 can be directly connected on board.

6 to 26.5 GHz Bandpass Filter Bank



Evaluation PC Board



Related Parts

Part Number				Description
AM3025A	0.4 GHz	to	6.0 GHz	Sub-Octave Bandpass Filter Bank
AM3152	0.4 GHz	to	8 GHz	Digitally Tunable Bandpass Filter
AM3153	6 GHz	to	26.5 GHz	Digitally Tunable Bandpass Filter



Component Compliance Information

RoHS: Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylheyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

REACH: Atlanta Micro, Inc. neither uses nor intentionally adds any of the substances considered to be a Substance of Very High Concern (SVHC) as defined by the EU Regulation (EC) No. 1907-2006 on Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH).

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Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.